Hongwei Tan

List of Publications by Year in descending order

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687363 888059 1,308 19 13 17 citations h-index g-index papers 19 19 19 1781 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	An Optoelectronic Resistive Switching Memory with Integrated Demodulating and Arithmetic Functions. Advanced Materials, 2015, 27, 2797-2803.	21.0	174
2	Light-Gated Memristor with Integrated Logic and Memory Functions. ACS Nano, 2017, 11, 11298-11305.	14.6	173
3	Thermally Stable Transparent Resistive Random Access Memory based on Allâ€Oxide Heterostructures. Advanced Functional Materials, 2014, 24, 2171-2179.	14.9	150
4	Energyâ€Efficient Organic Ferroelectric Tunnel Junction Memristors for Neuromorphic Computing. Advanced Electronic Materials, 2019, 5, 1800795.	5.1	144
5	Tactile sensory coding and learning with bio-inspired optoelectronic spiking afferent nerves. Nature Communications, 2020, 11, 1369.	12.8	141
6	Bioinspired multisensory neural network with crossmodal integration and recognition. Nature Communications, 2021, 12, 1120.	12.8	94
7	A 1D Vanadium Dioxide Nanochannel Constructed via Electricâ€Fieldâ€Induced Ion Transport and its Superior Metal–Insulator Transition. Advanced Materials, 2017, 29, 1702162.	21.0	79
8	Convertible resistive switching characteristics between memory switching and threshold switching in a single ferritin-based memristor. Chemical Communications, 2016, 52, 4828-4831.	4.1	71
9	Thermally-stable resistive switching with a large ON/OFF ratio achieved in poly(triphenylamine). Chemical Communications, 2014, 50, 11856-11858.	4.1	69
10	Synaptic plasticity and learning behaviours in flexible artificial synapse based on polymer/viologen system. Journal of Materials Chemistry C, 2016, 4, 3217-3223.	5. 5	61
11	Role of oxadiazole moiety in different D–A polyazothines and related resistive switching properties. Journal of Materials Chemistry C, 2013, 1, 4556.	5.5	56
12	An organic terpyridyl-iron polymer based memristor for synaptic plasticity and learning behavior simulation. RSC Advances, 2016, 6, 25179-25184.	3.6	48
13	Mimicking Neurotransmitter Release and Longâ€Term Plasticity by Oxygen Vacancy Migration in a Tunnel Junction Memristor. Advanced Intelligent Systems, 2019, 1, 1900036.	6.1	17
14	Crossover from synaptic to neuronal functionalities through carrier concentration control in Nb-doped SrTiO3-based organic ferroelectric tunnel junctions. APL Materials, 2019, 7, 091114.	5.1	16
15	Reversible Luminescence Modulation upon an Electric Field on a Full Solid-State Device Based on Lanthanide Dimers. ACS Applied Materials & Samp; Interfaces, 2016, 8, 15551-15556.	8.0	8
16	Multifunctional Optoelectronic Device Based on Resistive Switching Effects., 0,,.		4
17	Transparent Electronics: Thermally Stable Transparent Resistive Random Access Memory based on Allâ€Oxide Heterostructures (Adv. Funct. Mater. 15/2014). Advanced Functional Materials, 2014, 24, 2110-2110.	14.9	2
18	Nanochannels: A 1D Vanadium Dioxide Nanochannel Constructed via Electricâ€Fieldâ€Induced Ion Transport and its Superior Metal–Insulator Transition (Adv. Mater. 39/2017). Advanced Materials, 2017, 29, .	21.0	1

#	Article	IF	CITATIONS
19	Switching Memory: An Optoelectronic Resistive Switching Memory with Integrated Demodulating and Arithmetic Functions (Adv. Mater. 17/2015). Advanced Materials, 2015, 27, 2812-2812.	21.0	O